

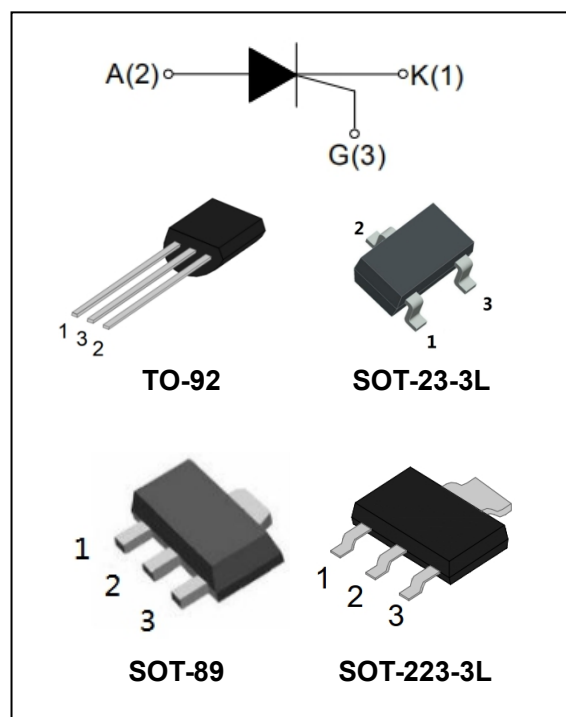
MCR100-6 Series 0.8A Sensitive SCRs

DESCRIPTION:

The MCR100-6 SCR series provide high dv/dt rate with strong resistance to electromagnetic interface. They are especially recommended for use on residual current circuit breaker, straight hair, igniter etc.

MAIN FEATURES:

symbol	value	unit
$I_{T(RMS)}$	1	A
V_{DRM}/V_{RRM}	400/600	V
V_{TM}	≤ 1.5	V



ABSOLUTE MAXIMUM RATINGS:

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40~150	°C
Operating junction temperature range	T_j	-40~110	°C
Repetitive peak off-state voltage ($T_j=25^{\circ}C$)	V_{DRM}	400/600	V
Repetitive peak reverse voltage ($T_j=25^{\circ}C$)	V_{RRM}	400/600	V
RMS on-state current	$I_{T(RMS)}$	0.8	A
Non repetitive surge peak on-state current (full cycle, F=50Hz)	I_{TSM}	8	A
I^2t value for fusing ($t_p=10ms$)	I^2t	0.32	A ² s
Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$)	di/dt	50	A/ μ s
Peak gate current	I_{GM}	0.2	A
Average gate power dissipation	$P_{G(AV)}$	0.1	W
Peak gate power	P_{GM}	0.5	W

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ELECTRICAL CHARACTERISTICS ($T_j=25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Test Condition	Value			Unit
		MIN	TYPE	MAX	
I_{GT}	$V_D=12\text{V}, R_L=33\Omega$	-	20	200	μA
V_{GT}		-	0.6	0.8	V
V_{GD}	$V_D=V_{DRM} T_j=110^{\circ}\text{C}$ $R_L=3.3\text{k}\Omega$	0.2	-	-	V
I_H	$I_T=50\text{mA}$	-	-	5	mA
I_L	$I_G=1.2I_{GT}$	-	-	6	mA
dV/dt	$V_D=0.66 \times V_{DRM} T_j=110^{\circ}\text{C}$ G open $R_{GK}=1\text{k}\Omega$	10	-	-	V/ μs

STATIC CHARACTERISTICS

Symbol	Test Condition			Value	Unit
V _{TM}	I _{TM} =1A t _p =380μs	T _j =25°C	MAX	1.5	V
I _{DRM}	V _{DRM} = V _{RRM} R _{GK} =1KΩ	T _j =25°C	MAX	5	μA
I _{RRM}		T _j =110°C		100	μA

THERMAL RESISTANCES

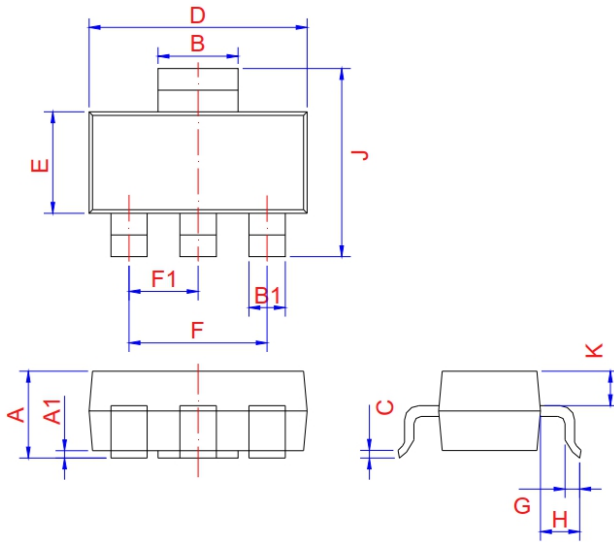
Symbol	Test Condition		Value	Unit
R _{th(j-c)}	结到外壳(AC)	SOT-223	31	°C/W
		TO-92	75	
		SOT-23-3L		
		SOT-89	45	

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ORDERING INFORMATION

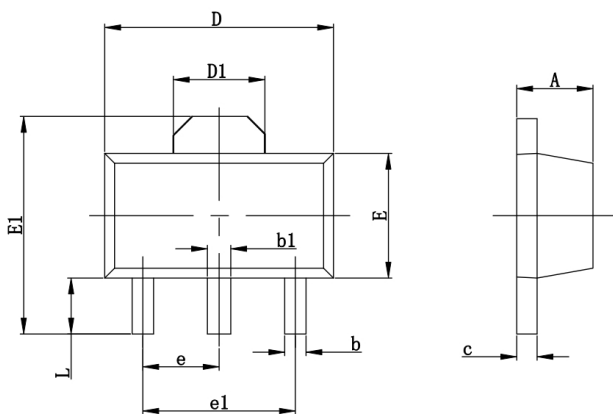
<u>M C R</u>	<u>1 0 0 - 6</u>	
SCR	$I_{T(RMS)}:0.8A$	$V_{DRM}, V_{RRM}:400V$

PACKAGE MECHANICAL DATA



SOT-223-3L

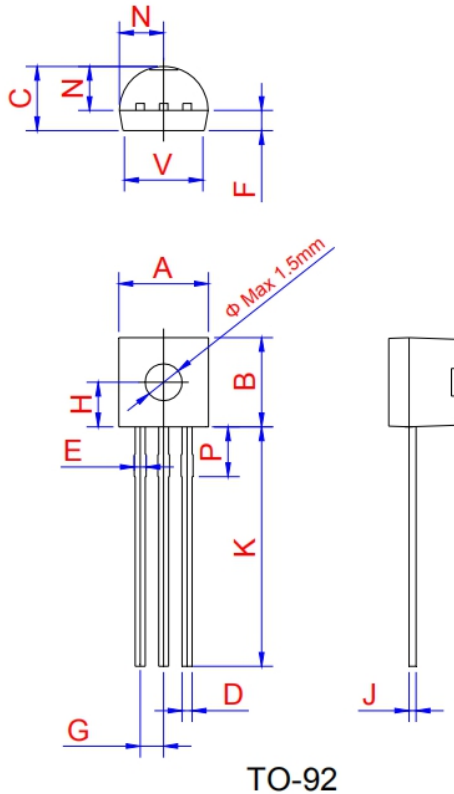
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	1.5	1.6	1.8	0.059	0.063	0.071
A1	0.01	0.06	0.10	0.001	0.002	0.004
B	2.9	3.0	3.1	0.114	0.118	0.122
B1	0.6	0.7	0.8	0.024	0.028	0.031
C	0.22	0.25	0.32	0.009	0.010	0.013
D	6.3	6.5	6.7	0.248	0.256	0.264
E	3.3	3.5	3.7	0.130	0.138	0.146
F		4.6	6.8	0.252	0.181	
F1		2.3			0.091	
G	0.7	0.9	1.1	0.028	0.035	0.043
H	1.5	1.75	2.0	0.059	0.069	0.079
J	6.7	7.0	7.3	0.264	0.276	0.287
K	0.8	0.9	1.0	0.031	0.035	0.039



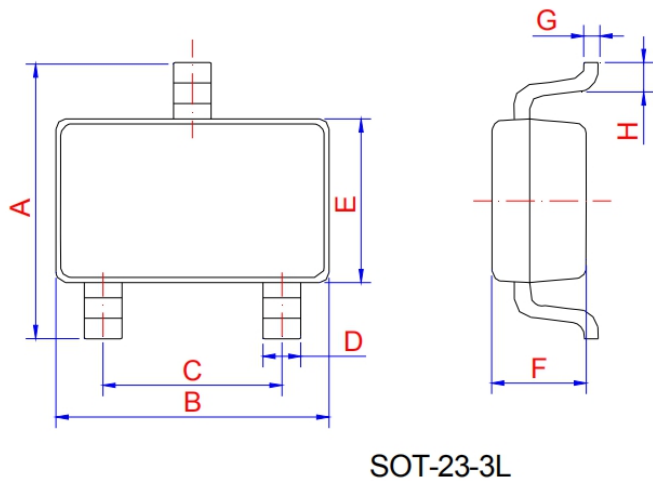
SOT-89-3L

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	1.4		1.6	0.055		0.063
b	0.35		0.52	0.013		0.197
b1	0.4		0.58	0.016		0.023
c	0.35		0.44	0.014		0.017
D	4.4		4.6	0.173		0.181
D1		1.55			0.061	
E	2.35		2.55	0.091		0.102
E1	3.94		4.25	0.155		0.167
e		1.500			0.060	
e1		3.000			0.118	
L	0.9		1.1	0.035		0.047

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Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.45	4.6	5.2	0.175	0.181	0.205
B	4.32	4.6	5.33	0.17	0.181	0.21
C	3.18	3.55	4.19	0.125	0.14	0.165
D	0.407		0.533	0.016		0.021
E	0.6		0.8	0.024	0	0.031
F	-	1.1	-	-	0.043	-
G	-	1.27	-	-	0.05	-
H	-	2.3	-	-	0.091	-
J	0.36	0.38	0.5	0.014	0.015	0.02
K	12.7		15	0.5		0.591
N	2.04	2.3	2.66	0.08	0.091	0.105
P	1.86		2.06	0.073		0.081
V	-		4.3	-		0.169



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.65	2.8	2.95	0.104	0.11	0.116
B	2.82	2.92	3.02	0.111	0.115	0.119
C	1.8	1.9	2	0.071	0.075	0.079
D	0.3	0.35	0.5	0.012	0.014	0.02
E	1.5	1.6	1.7	0.059	0.063	0.067
F	1.07	1.17	1.27	0.042	0.046	0.05
G	0.05	0.15	0.25	0.002	0.006	0.01
H	0.25	0.4	0.55	0.01	0.016	0.022

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FIG.1: Maximum power dissipation versus RMS on-state current

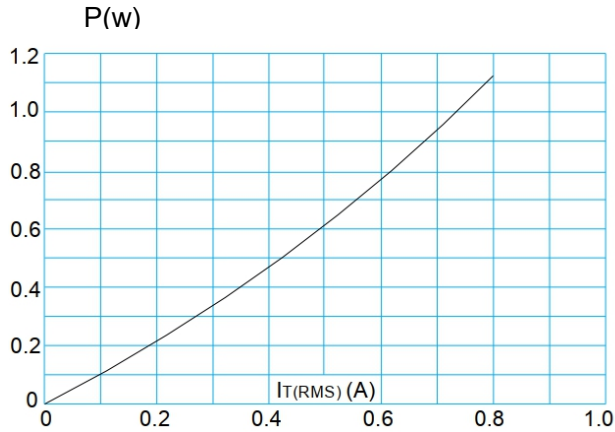


FIG.2: RMS on-state current versus case temperature

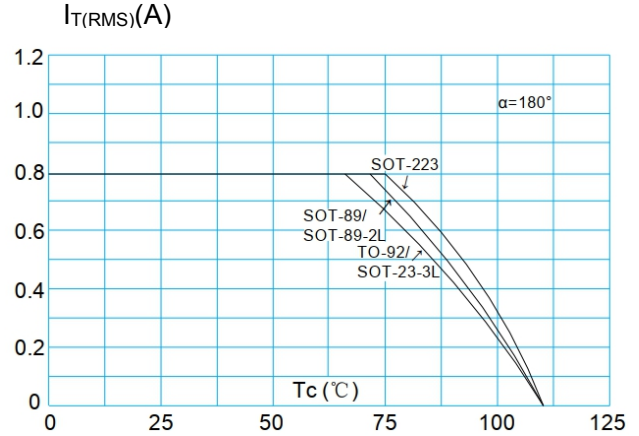


FIG.3: Surge peak on-state current versus number of cycles

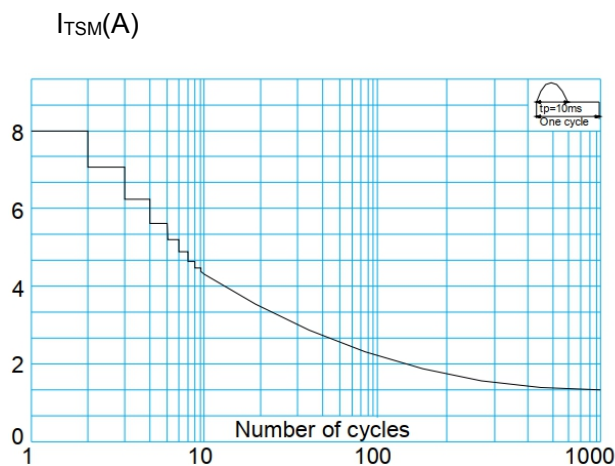


FIG.4: On-state characteristics (maximum values)

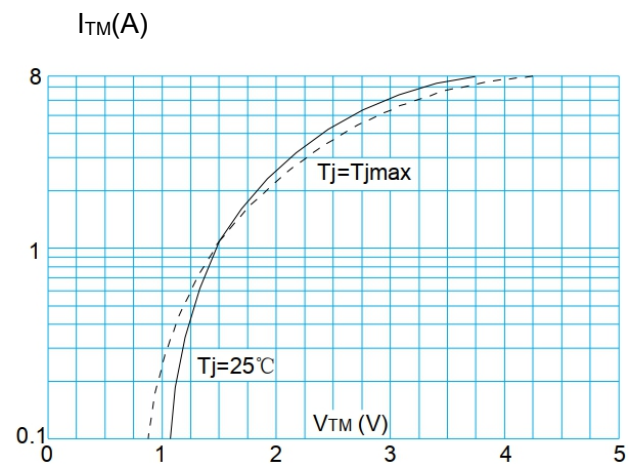


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20ms$, and corresponding value of $I^2 t$ ($di/dt < 50A/\mu s$)

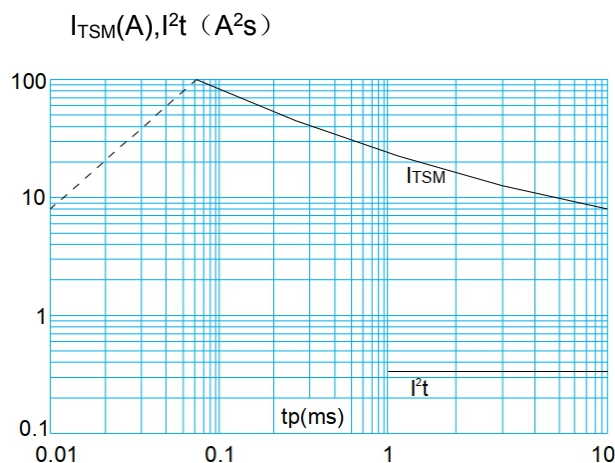


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature

